Am27S31/27S31A

(512x8) Bipolar PROM



DISTINCTIVE CHARACTERISTICS

- High speed -- 35 ns max commercial range access time
- Excellent performance over full military and commercial ranges
- Highly reliable, ultra-fast programming Platinum-Silicide fuses
- · High programming yield
- Low current PNP inputs
- · High current and three-state outputs
- Fast chip select

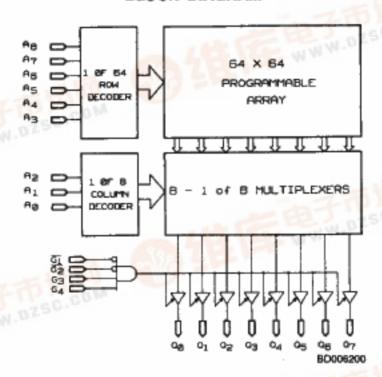
GENERAL DESCRIPTION

The Am27S31 (512 words by 8 bits) is a Schottky TTL Programmable Read-Only Memory (PROM).

This device is available in three-state output version compatible with low-power Schottky bus standards capable

of satisfying the requirements of a variety of microprogrammable controls, mapping functions, code conversion, or logic replacement. Easy word-depth expansion is facilitated by both active LOW (G₁ and G₂) and active HIGH (G₃ and G₄) output enables.

BLOCK DIAGRAM

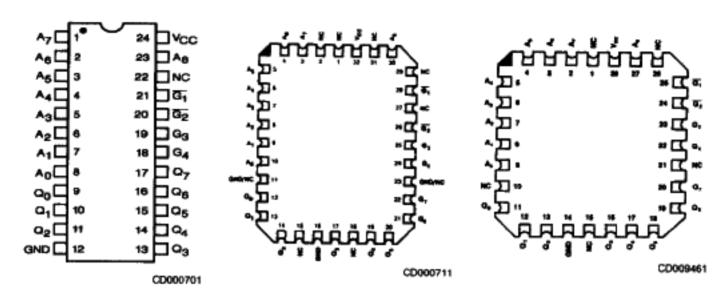


PRODUCT SELECTOR GUIDE

Part Number	Am27	'531A	Am27S31			
Address Access Time	35 ns	45 ns	55 ns	70 ns		
Operating Range	С	м	С	М		



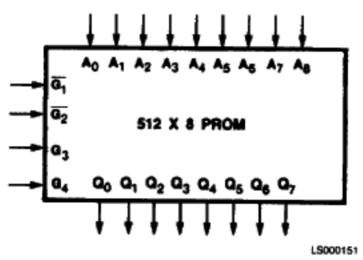
LCCs**



- "Also available in a 24-Pin Flatpack. Pinout identical to DIPs.
- **Also available in a 28-Pin Square PLCC. Pinout identical to LCC.

Note: Pin 1 is marked for orientation.

LOGIC SYMBOL



V_{CC}/ = Power Supply

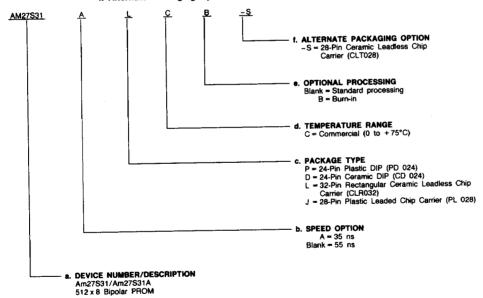
GND/ = Ground

ORDERING INFORMATION

Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of: a. Device Number

- a. Device Number
 b. Speed Option (if applicable)
 c. Package Type
 d. Temperature Range
 e. Optional Processing
 f. Alternate Packaging Option



Valid Co	Valid Combinations PC PCB DC DCB.							
AM27S31	PC, PCB, DC, DCB, LC, LC-S, LCB, LCB-S,							
AM27S31A	JC, JCB							

Valid Combinations

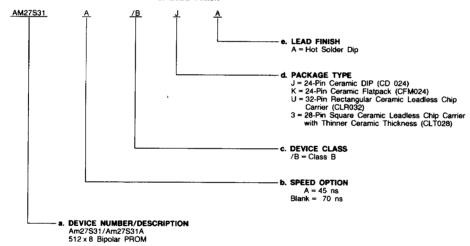
Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released valid combinations, and to obtain additional data on AMD's standard military grade products. grade products.

MILITARY ORDERING INFORMATION

APL Products

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. APL (Approved Products List) products are fully compliant with MIL-STD-883C requirements. The order number (Valid Combination) for APL products is formed by a combination of: a. Device Number

- b. Speed Option (if applicable)
- c. Device Class
- d. Package Type e. Lead Finish



Valid Combinations								
AM27S31	/BJA, /BKA,							
AM27S31A	/BUA, /B3A							

Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations or to check for newly released valid

Group A Tests

Group A tests consist of Subgroups 1, 2, 3, 7, 8, 9, 10, 11.

MILITARY BURN-IN

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Method 1015, Conditions A through E. Test conditions are selected at AMD's option.

PIN DESCRIPTION

A₀ – A₈ Address Inputs

The 9-bit field presented at the address inputs selects one of 512 memory locations to be read from.

Q₀ - Q₇ Data Output Port

The Outputs whose state represents the data read from the selected memory locations.

G1, G2, G3, G4 Output Enable

Provides direct control of the Q-output buffers. Outputs disabled forces all three-state outputs to a floating or highimpedance state.

Enable =
$$\overline{G_1} \cdot \overline{G_2} \cdot G_3 \cdot G_4$$

Disable =
$$\overline{G_1 \cdot G_2 \cdot G_3 \cdot G_4}$$

= $G_1 + G_2 + \overline{G_3} + \overline{G_4}$

V_{CC} Device Power Supply Pin
The most positive of the logic power supply pins.

GND Device Power Supply Pin

The most negative of the logic power supply pins.

ABSOLUTE MAXIMUM RATINGS

Storage Temperature-65 to +150°C Ambient Temperature with DC Voltage Applied to Outputs DC input Voltage -0.5 V to +5.5 V DC Input Current-30 mA to +5 mA

Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

OPERATING RANGES

Commercial (C) Devices Ambient Temperature (T _A) Supply Voltage (V _{CC})	0 to +75°C
Military (M) Devices* Case Temperature (T _C)	55 to +125°C
Supply Voltage (VCC)	+ 4.5 V to +5.5 V
a u define these lie	nite hatween which the

Operating ranges define those limits between which the functionality of the device is guaranteed.

*Military Product 100% tested at $T_C = +25$ °C, +125°C, and -55°C.

DC CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 1, 2, 3 are tested unless otherwise noted)

Parameter Symbol	Parameter Description		Min.	Тур.	Max.	Unit		
V _{OH} (Note 1)	Output HIGH Voltage	V _{CC} = Min., loi V _{IN} = V _{IH} or V	2.4			٧		
VOL	Output LOW Voltage	V _{CC} = Min., I _O V _{IN} = V _{IH} or V			0.50	٧		
ViH	Input HIGH Level	Guaranteed ing	2.0			٧		
ViL	Input LOW Level	Guaranteed ing			0.8	٧		
l _{IL}	Input LOW Current	V _{CC} = Max., V			-0.250	mA		
In In	Input HIGH Current	V _{CC} = Max., V			25	μΑ		
Isc (Note 1)	Output Short-Circuit Current	V _{CC} = Max., V	-20	<u> </u>	-90	mA		
loc	Power Supply Current	All inputs = GN V _{CC} = Max.			175	mA		
VI	Input Clamp Voltage	V _{CC} = Min., 1 _{IN}	=-18 mA				-1.2	
*				Vo = Vcc			40	
CEX	Output Leakage Current	V _{CC} = Max. V _G = 2.4 V		Vo = 2.4 V			40	μΑ
'UEA		VG = 2.4 V (Note 1) V _O = 0.4 V				I	-40	
C _{IN}	Input Capacitance	V _{IN} = 2.0 V @ f = 1 MHz (Note 4) V _{CC} = 5 V, T _A = 25°C				4		DF
Cout	Output Capacitance	V _{OUT} = 2.0 V V _{CC} = 5 V, T _A		8				

- Notes: 1. This applies to three-state devices only.

 2. V_{IL} and V_{IH} are input conditions of output tests and are not themselves directly tested. V_{IL} and V_{IH} are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.

 3. Not more than one output should be shorted at a time. Duration of the short circuit should not be more than one second.

 4. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

SWITCHING CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 9, 10, 11 are tested unless otherwise noted*)

No.	Parameter Symbol	r Parameter Description	Am27S31A				Am27S31				Γ
			COM'L.		MIL		COM'L		MIL		
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
1	TAVQV	Address Valid to Output Valid Access Time		35		45		55		70	ns
2	TGVQZ	Delay from Output Enable Valid to Output Hi-Z		20		25		25		30	ns
3	TGVQV	Delay from Output Enable Valid to Output Valid		20		25		25		30	ns

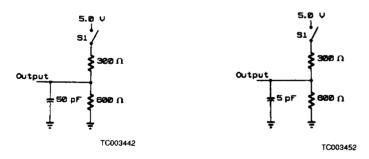
See also Switching Test Circuits.

Notes: 1. Tests are performed with input transition time of 5 ns or less, timing reference levels of 1.5 V, and input pulse levels of 0 to 3.0 V using test load in A under Switching Test Circuits.

2. TGVQZ is measured at steady state HIGH output voltage ~0.5 V and steady state LOW output voltage +0.5 V ouput levels using the test load in B under Switching Test Circuits.

*Subgroups 7 and 8 apply to functional tests.

SWITCHING TEST CIRCUITS



A. Output Load for all A - C tests except TGVQZ

B. Output Load for TGVQZ

Notes: 1. All device test loads should be located within 2" of device output pin.

2. S_1 is open for Output Data HIGH to Hi-Z and Hi-Z to Output Data HIGH tests. S_1 is closed for all other AC tests.

3. Load capacitance includes all stray and fixture capacitance.

SWITCHING WAVEFORMS KEY TO SWITCHING WAVEFORMS

